



# 2N5114, 2N5115, 2N5116 P-Channel JFET

#### Features

- InterFET P0099F Geometry
- Typical Noise: 8 nV/VHz
- Low Rds(on)
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

## Applications

- Analog Switches
- Choppers

#### Description

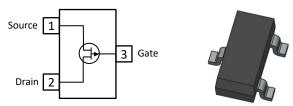
The 30V InterFET 2N5114, 2N5115, and 2N5116 are targeted for choppers and analog switch designs. The on resistance is typically less than 100 Ohms at room temperatures. The TO-18 package is hermetically sealed and suitable for military applications.

# Drain Gate/Case

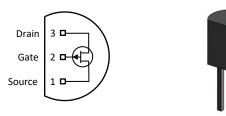




**TO-18 Bottom View** 







#### **Product Summary**

	Parameters	2N5114 Min	2N5115 Min	2N5116 Min	Unit
$BV_{GSS}$	Gate to Source Breakdown Voltage	30	30	30	V
I <sub>DSS</sub>	Drain to Source Saturation Current	-30	-15	-5	mA
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	5	3	1	V

## Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
2N5114; 2N5115; 2N5116	Through-Hole	TO-18	Bulk
PN5114; PN5115; PN5116	Through-Hole	TO-92	Bulk
SMP5114; SMP5115;			
SMP5116	Surface Mount	SOT23	Bulk
SMP5114TR; SMP5115TR	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMP5116TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
2N5114COT; 2N5115COT			
2N5116COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack
2N5114CFT; 2N5115CFT			
2N5116CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



**Disclaimer:** It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.







# **Electrical Characteristics**

#### Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

	Parameters	Value	Unit	
VRGS	Reverse Gate Source and Gate Drain Voltage	30	V	
$I_{FG}$	Continuous Forward Gate Current	50	mA	
PD	Continuous Device Power Dissipation	500	mW	
Р	Power Derating	4	mW/°C	
Τı	Operating Junction Temperature	-55 to 125	°C	
T <sub>STG</sub>	Storage Temperature	-65 to 200	°C	

## Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			2N5114		2N5115		2N5116		
	Parameters	Conditions	Min	Max	Min	Max	Min	Max	Unit
V(BR)GSS	Gate to Source Breakdown Voltage	V <sub>DS</sub> = 0V, I <sub>G</sub> = -1mA	30		30		30		v
I <sub>GSS</sub>	Gate to Source Reverse Current	V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V, T <sub>A</sub> = 25°C V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V, T <sub>A</sub> = 150°C		2 10		2 10		2 10	nA μA
Vgs(off)	Gate to Source Cutoff Voltage	V <sub>DS</sub> = -15V, I <sub>D</sub> = -1nA	5	10	3	6	1	4	v
V <sub>GS(F)</sub>	Gate to Source Forward Voltage	V <sub>DS</sub> = 0V, I <sub>G</sub> = -1mA		-1		-1		-1	v
I <sub>DSS</sub>	Drain to Source Saturation Current	$V_{GS} = 18V, V_{DS} = -15V$ $V_{GS} = 15V, V_{DS} = -15V$ (Pulsed)	-30	-90	-15	-60	-5	-25	mA
Id(off)	Drain Cutoff Current	V <sub>DS</sub> = -15V, V <sub>GS</sub> = 12V, T <sub>A</sub> = 25°C V <sub>DS</sub> = -15V, V <sub>GS</sub> = 7V, T <sub>A</sub> = 150°C		-2 -10		-2 -10		-2 -10	nA μA
	Ducia ta Cauna	$V_{GS} = 0V, I_{D} = -15mA$		-1.3					
V <sub>DS(ON)</sub>	Drain to Source	$V_{GS} = 0V, I_D = -7mA$				-0.8			V
	ON Voltage	$V_{GS} = 0V, I_D = -3mA$						-0.6	
R <sub>DS(ON)</sub>	Static Drain to Source ON Resistance	$V_{GS} = 0V$ , $I_D = -1mA$		75		100		150	Ω

#### Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

			2N5114		2N5115		2N5116		
	Parameters	Conditions	Min	Max	Min	Max	Min	Max	Unit
R <sub>DS(ON)</sub>	Drain to Source ON Resistance	$V_{GS}$ = 0V, $I_D$ = 0A, f = 1kHz		75		100		150	Ω
Ciss	Input Capacitance	$V_{DS}$ = -15V, $V_{GS}$ = 0V, f = 1MHz		25		25		27	рF
	Reverse Transfer Capacitance	V <sub>DS</sub> = -10V, V <sub>GS</sub> = 12V, f = 1MHz		7					
Crss		V <sub>DS</sub> = -10V, V <sub>GS</sub> = 7V, f = 1MHz				7			рF
		V <sub>DS</sub> = -10V, V <sub>GS</sub> = 5V, f = 1MHz						7	
t <sub>d(ON)</sub>	Turn-On Delay Time	V <sub>DD</sub> = V		6		10		25	ns
tr	Rise Time	V <sub>DD</sub> = V		10		20		35	ns
t <sub>d(OFF)</sub>	Turn-Off Delay Time	V <sub>DD</sub> = V		6		8		20	ns
t <sub>f</sub>	Fall Time	V <sub>DD</sub> = V		15		30		60	ns



Technical

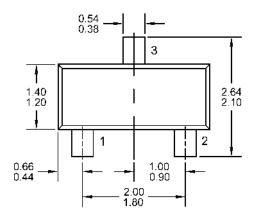
Support

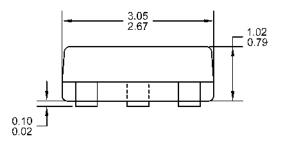
Order

Now

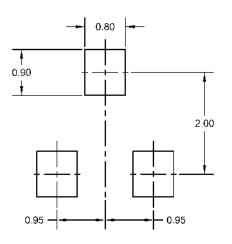
# SOT23 (TO-236AB) Mechanical and Layout Data

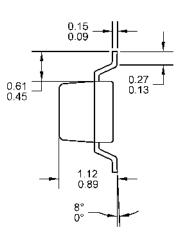
#### Package Outline Data





## Suggested Pad Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.



Technical Support

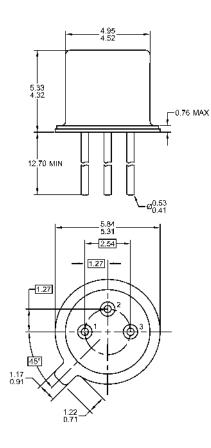
Order

Now

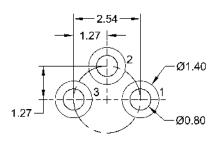
# 2N5114-5-6

# **TO-18 Mechanical and Layout Data**

## **Package Outline Data**



## Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.29 grams
- 3. Bulk product is shipped in standard ESD shipping material
- 4. Refer to JEDEC standards for additional information.

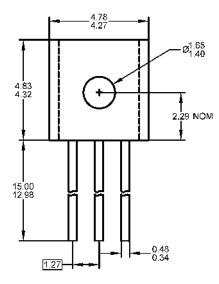
- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

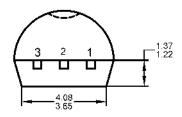




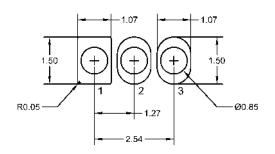
# **TO-92 Mechanical and Layout Data**

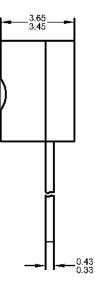
## **Package Outline Data**





# Suggested Through-Hole Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.